TOSHIBA Transistor Silicon-Germanium NPN Epitaxial Planar Type

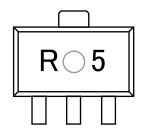
# MT3S111P

VHF-UHF Low-Noise, Low-Distortion Amplifier Applications

#### **Features**

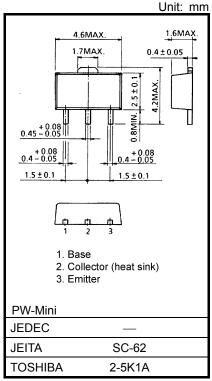
- Low-Noise Figure: NF=0.95 dB (typ.) (@f=1 GHz)
- High Gain: |S<sub>21e</sub>|<sup>2</sup>=10.5 dB (typ.) (@f=1 GHz)

#### Marking



### Absolute Maximum Ratings (Ta = 25°C)

| Characteristics             | Symbol                  | Rating     | Unit |
|-----------------------------|-------------------------|------------|------|
| Collector-emitter voltage   | V <sub>CES</sub>        | 13         | V    |
| Collector-emitter voltage   | V <sub>CEO</sub>        | 6          | V    |
| Emitter-base voltage        | V <sub>EBO</sub>        | 0.6        | V    |
| Collector-current           | Ic                      | 100        | mA   |
| Base-current                | ΙΒ                      | 10         | mA   |
| Collector power dissipation | PC                      | 300        | mW   |
| Collector power dissipation | P <sub>C</sub> (Note 1) | 1          | W    |
| Junction temperature        | Tj                      | 150        | °C   |
| Storage temperature range   | T <sub>stg</sub>        | -55 to 150 | °C   |



Weight:0.05 g (typ.)

Note 1: The device is mounted on a ceramic board (16 mm × 16 mm × 0.8 mm (t))

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2007-11



### **Microwave Characteristics (Ta = 25°C)**

| Characteristics   | Symbol                              | Test Condition  | Min | Тур. | Max  | Unit |
|---|-------------------------------------|---|-----|------|------|------|
| Transition frequency  | f <sub>T</sub>                      | V <sub>CE</sub> =5 V, I <sub>C</sub> =30 mA             | 6   | 8    | _    | GHz  |
| Insertion gain  | S <sub>21e</sub>   <sup>2</sup> (1) | V <sub>CE</sub> =5 V, I <sub>C</sub> =30 mA, f=500 MHz  | _   | 16   | _    | dB   |
|   | S <sub>21e</sub>   <sup>2</sup> (2) | V <sub>CE</sub> =5 V, I <sub>C</sub> =30 mA, f=1 GHz    | 8.5 | 10.5 | _    | dB   |
| Noise figure  | NF(1)                               | V <sub>CE</sub> =5 V, I <sub>C</sub> =30 mA, f=500 MHz  | _   | 0.7  | _    | dB   |
|   | NF(2)                               | V <sub>CE</sub> =5 V, I <sub>C</sub> =30 mA, f=1 GHz    | _   | 0.95 | 1.25 | dB   |
| 3 <sup>rd</sup> order intermodulation distortion output intercept point | OIP <sub>3</sub>                    | V <sub>CE</sub> =5 V, I <sub>C</sub> =30 mA, f=500 MHz, |     | 32   | _    | dBmW |
|   |                                     | ⊿f=1 MHz  |     |      |      |      |

### **Electrical Characteristics (Ta = 25°C)**

| Characteristics              | Symbol           | Test Condition  | Min | Тур. | Max | Unit |
|------------------------------|------------------|---|-----|------|-----|------|
| Collector cut-off current    | I <sub>CBO</sub> | V <sub>CB</sub> =5 V, I <sub>E</sub> =0 A                   | _   | _    | 0.1 | μΑ   |
| DC current gain              | h <sub>FE</sub>  | V <sub>CE</sub> =5 V, I <sub>C</sub> =30 mA                 | 200 | _    | 400 | _    |
| Output capacitance           | C <sub>ob</sub>  | V <sub>CB</sub> =5 V, I <sub>E</sub> =0 A, f=1 MHz          | _   | 1.6  | _   | pF   |
| Reverse transfer capacitance | C <sub>re</sub>  | V <sub>CB</sub> =5 V, I <sub>E</sub> =0 A, f=1 MHz (Note 2) |     | 1    | 1.3 | pF   |

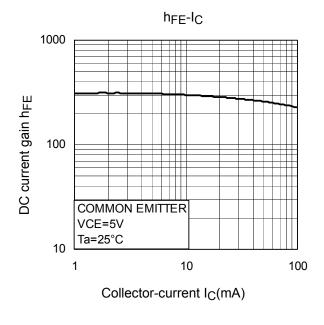
Note 2:  $C_{\mbox{re}}$  is measured using a 3-terminal method with capacitance bridge.

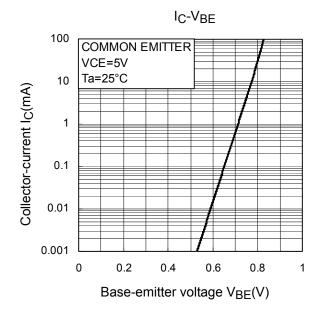
#### Caution:

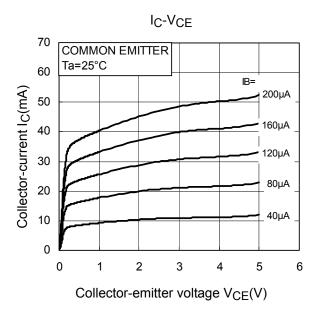
This device is sensitive to electrostatic discharge due to the high frequency transistor process of

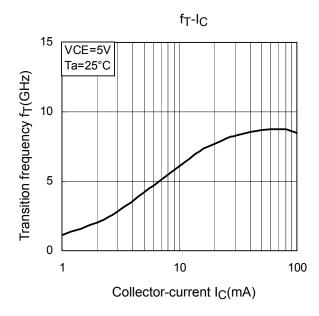
 $f_T$ =60 GHz class which is used for this product.

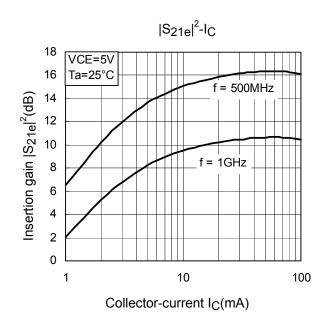
Please make tool and equipment earthed enough when you handle.

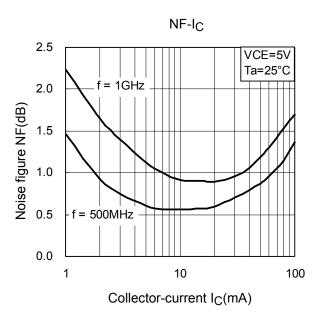


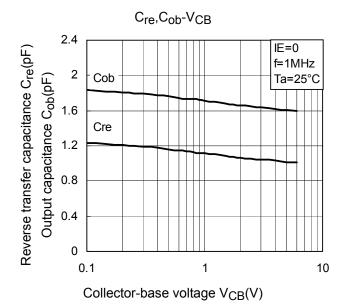


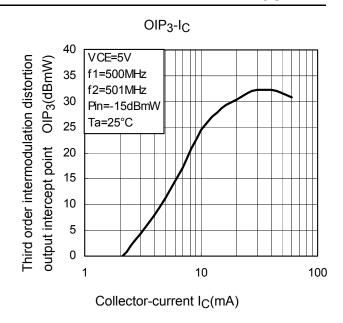


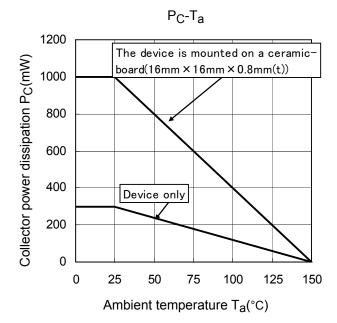












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